RENESAS 2.5V Single Data Rate 1:10 Clock Buffer Terabuffer™ Jr.

PRODUCT DISCONTINUATION NOTICE - LAST TIME BUY EXPIRES SEPTEMBER 7, 2016 DATASHEET

FEATURES:

- Optimized for 2.5V LVTTL
- Guaranteed Low Skew < 125ps (max)
- Very low duty cycle distortion < 300ps (max)
- High speed propagation delay < 2ns. (max)
- Up to 200MHz operation
- Very low CMOS power levels
- · Hot insertable and over-voltage tolerant inputs
- 1:10 fanout buffer
- 2.5V VDD
- Available in TSSOP package
- NOT RECOMMENDED FOR NEW DESIGNS
- For replacement part use 8T39S11

APPLICATIONS:

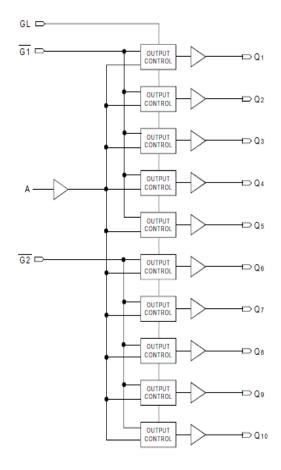
· Clock and signal distribution

FUNCTIONAL BLOCK DIAGRAM

DESCRIPTION:

The 5t9070 2.5V single data rate (SDR) clock buffer is a single-ended input to ten single-ended outputs buffer built on advanced metal CMOS technology. The SDR clock buffer fanout from a single input to ten single-ended outputs reduces the loading on the preceding driver and provides an efficient clock distribution network.

The 5t9070 has two output banks that can be asynchronously enabled/ disabled. Multiple power and grounds reduce noise.



PIN CONFIGURATION

| | [| | - ٦ | | 1 | |
|-----|---|----|--------|----|---|-----|
| GL | | 1 | \cup | 48 | | GND |
| Vod | | 2 | | 47 | | VDD |
| Vod | | 3 | | 46 | | VDD |
| GND | | 4 | | 45 | | GND |
| GND | | 5 | | 44 | | GND |
| G1 | | 6 | | 43 | | GND |
| Vod | | 7 | | 42 | | VDD |
| Q2 | | 8 | | 41 | | Q3 |
| Q1 | | 9 | | 40 | | Q4 |
| GND | | 10 | | 39 | | GND |
| Vod | | 11 | | 38 | | VDD |
| GND | | 12 | | 37 | | Q5 |
| A | | 13 | | 36 | | Q6 |
| Vod | | 14 | | 35 | | VDD |
| GND | | 15 | | 34 | | GND |
| Q10 | | 16 | | 33 | | Q7 |
| Q9 | | 17 | | 32 | | Q8 |
| Vod | | 18 | | 31 | | VDD |
| G2 | | 19 | | 30 | | VDD |
| GND | | 20 | | 29 | | GND |
| GND | | 21 | | 28 | | GND |
| Vod | | 22 | | 27 | | VDD |
| Vod | | 23 | | 26 | | GND |
| NC | | 24 | | 25 | | NC |
| | - | T | SSOI | | | |
| | 1 | 0 | P VIE | .W | | |

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

| Symbol | Description | Max | Unit |
|--------|----------------------|------------------|------|
| VDD | Power Supply Voltage | -0.5 to +3.6 | V |
| VI | Input Voltage | -0.5 to +3.6 | V |
| Vo | Output Voltage | -0.5 to VDD +0.5 | V |
| TSTG | Storage Temperature | –65 to +165 | °C |
| τJ | Junction Temperature | 150 | °C |

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE⁽¹⁾ (TA = +25°C, F = 1.0MHz)

| Svn | nbol | Parameter | Min | Tvp. | Max. | Unit |
|-----|------|-------------------|-----|------|------|------|
| Cin | | Input Capacitance | _ | 6 | _ | pF |

NOTE:

1. This parameter is measured at characterization but not tested.

RECOMMENDED OPERATING RANGE

| Symbol | Description | Min. | Tvp. | Max. | Unit |
|--------|-------------------------------|------|------|------|------|
| ТА | Ambient Operating Temperature | -40 | +25 | +85 | °C |
| Vdd | Internal Power Supply Voltage | 2.3 | 2.5 | 2.7 | V |

PIN DESCRIPTION

| Symbol | I/O | Туре | Description |
|--------|-----|-------|---|
| A | | | Clock input |
| G1 | I | LVTTL | Gate for outputs Q1 through Q5. When $\overline{G1}$ is LOW, these outputs are enabled. When $\overline{G1}$ is HIGH, these outputs are asynchro- nously disabled to the level designated by GL ⁽¹⁾ . |
| G2 | I | LVTTL | Gate for outputs Q ₆ through Q ₁₀ . When $\overline{G2}$ is LOW, these outputs are enabled. When $\overline{G2}$ is HIGH, these outputs are asyn- chronously disabled to the level designated by GL ⁽¹⁾ . |
| GL | | LVTTL | Specifies output disable level. If HIGH, the outputs disable HIGH. If LOW, the outputs disable LOW. |
| Qn | 0 | LVTTL | Clock outputs |
| Vdd | | PWR | Power supply for the device core, inputs, and outputs |
| GND | | PWR | Power supply return for power |

NOTE:

1. Because the gate controls are asynchronous, runt pulses are possible. It is the user's responsibility to either time the gate control signals to minimize the possibility of runt pulses or be able to tolerate them in down stream circuitry.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE ⁽¹⁾

| Symbol | Parameter | Test Conditions | Min. | Typ. ⁽⁴⁾ | Max | Unit |
|--------|------------------------------|-------------------------|-----------|---------------------|-------|------|
| LiH | Input HIGH Current | VDD = 2.7V VI = VDD/GND | _ | _ | ±5 | μA |
| lı. | Input LOW Current | VDD = 2.7V VI = GND/VDD | _ | _ | ±5 | |
| Vik | Clamp Diode Voltage | Vdd = 2.3V, Iin = -18mA | _ | - 0.7 | - 1.2 | V |
| VIN | DC Input Voltage | | - 0.3 | | +3.6 | V |
| Vih | DC Input HIGH ⁽²⁾ | | 1.7 | | _ | V |
| VIL | DC Input LOW ⁽³⁾ | | _ | | 0.7 | V |
| Voн | Output HIGH Voltage | Іон = -12mA | Vdd - 0.4 | | | V |
| | | Iон = -100 u A | Vdd - 0.1 | | _ | V |
| Vol | Output LOW Voltage | $I_{OL} = 12 \text{mA}$ | _ | | 0.4 | V |
| | | Iol = 100µA | - | | 0.1 | V |

NOTES:

1. See RECOMMENDED OPERATING RANGE table.

2. Voltage required to maintain a logic HIGH.

3. Voltage required to maintain a logic LOW.

4. Typical values are at VDD = 2.5V, +25°C ambient.

POWER SUPPLY CHARACTERISTICS

| Symbol | Parameter | Test Conditions ⁽¹⁾ | Тур. | Max | Unit |
|--------|--|---|------|-----|--------|
| Iddq | Quiescent Vbb Power Supply Current Vbb = Max., Reference Clock = LOW | | 1.5 | 2 | mA |
| | | Outputs enabled, All outputs unloaded | | | |
| Iddd | Dynamic Vod Power Supply Current per Output | VDD = Max., VDD = Max., CL = 0pF | 150 | 200 | µA/MHz |
| Ітот | Total Power Vod Supply Current | Vdd = 2.5V., Freference clock = 100MHz, Cl = 15pF | 70 | 90 | mA |
| | | VDD = 2.5V., FREFERENCE CLOCK = 200MHz, CL = 15pF | 100 | 150 | |

NOTE:

1. The termination resistors are excluded from these measurements.

INPUT AC TEST CONDITIONS

| Symbol | Parameter | Value | Units |
|--------|---|-------|-------|
| Vih | Input HIGH Voltage | Vdd | V |
| VIL | Input LOW Voltage | 0 | V |
| Vтн | Input Timing Measurement Reference Level ⁽¹⁾ | VDD/2 | V |
| tr, tr | Input Signal Edge Rate ⁽²⁾ | 2 | V/ns |

NOTES:

1. A nominal 1.25V timing measurement reference level is specified to allow constant, repeatable results in an automatic test equipment (ATE) environment.

2. The input signal edge rate of 2V/ns or greater is to be maintained in the 10% to 90% range of the input waveform.

AC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE⁽⁴⁾

| Symbol | Parameter | Min. | Тур. | Max | Unit |
|------------------|--|------|------|-----|------|
| Skew Parameters | | | 1 | 1 | |
| <u>tsк(o)</u> | Same Device Output Pin-to-Pin Skew ⁽¹⁾ | | _ | 125 | ps |
| tsk(p) | Pulse Skew ⁽²⁾ | | | 300 | ps |
| tsk(pp) | Part-to-Part Skew ⁽³⁾ | - | _ | 300 | ps |
| Propagation Dela | y l | | 1 | • | |
| t PLH | Propagation Delay A to Qn | - | - | 2 | ns |
| tphl | | | | | |
| tr | Output Rise Time (20% to 80%) | 350 | | 850 | ps |
| tF | Output Fall Time (20% to 80%) | 350 | | 850 | ps |
| fo | Frequency Range | _ | - | 200 | MHz |
| Output Gate Enab | ole/Disable Delay | • | | • | |
| T PGE | Output Gate Enable to Qn | | | 3.5 | ns |
| tpgd | Output Gate Enable to Qn Driven to GL Designated Level | — | - | 3 | ns |

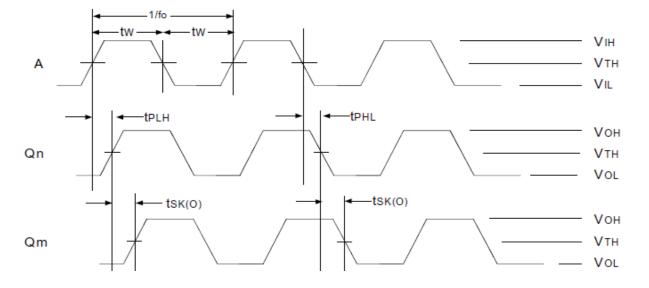
NOTES:

1. Skew measured between all outputs under identical input and output transitions and load conditions on any one device.

2. Skew measured is the difference between propagation delay times tPHL and tPLH of any output under identical input and output transitions and load conditions on any one device.

3. Skew measured is the magnitude of the difference in propagation times between any outputs of two devices, given identical transitions and load conditions at identical VDD levels and

temperature.



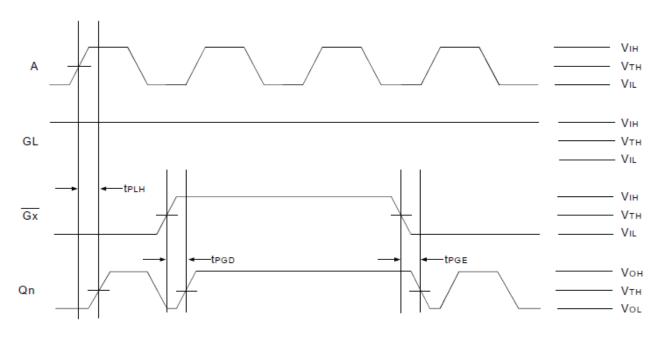
AC TIMING WAVEFORMS

Propagation and Skew Waveforms

NOTE: Pulse Skew is calculated using the following expression:

tsk(p) = | tphl - tplh |

where tPHL and tPLH are measured on the controlled edges of any one output from rising and falling edges of a single pulse. Please note that the tPHL and tPLH shown are not valid measurements for this calculation because they are not taken from the same pulse.

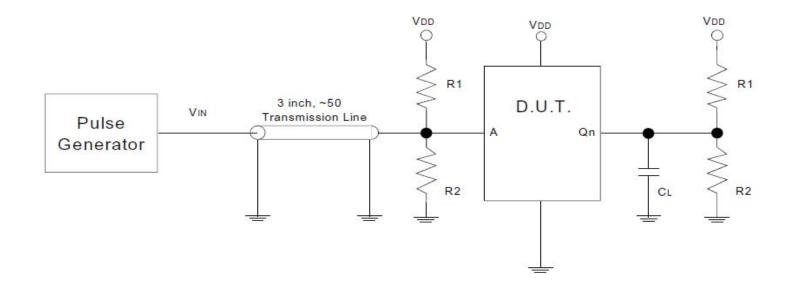


Gate Disable/Enable Runt Pulse Generation

NOTE:

As shown, it is possible to generate runt pulses on gate disable and enable of the outputs. It is the user's responsibility to time their \overline{Gx} signals to avoid this problem.

TEST CIRCUIT AND CONDITIONS

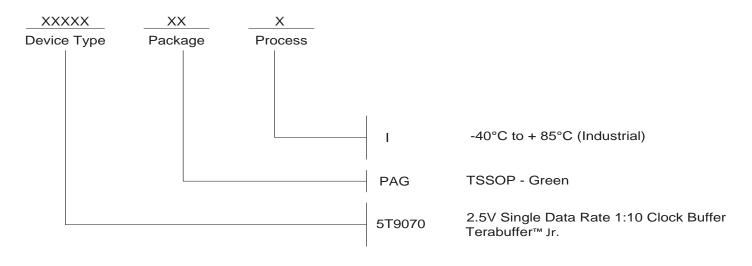


Test Circuit for Input/Output

| Symbol | $V_{DD} = 2.5V \pm 0.2V$ | Unit |
|--------|--------------------------|------|
| VTH | Vdd / 2 | V |
| R1 | 100 | Ω |
| R2 | 100 | Ω |
| CL | 15 | pF |

INPUT/OUTPUT TEST CONDITIONS

ORDERING INFORMATION



REVISION HISTORY

| Rev | Table | Page | Discription of Change | Date |
|-----|-------|------|--|---------|
| A | | 1 | NRND - Not Recommended for New Designs | 5/5/13 |
| А | | 7 | Ordering Information - removed PA leaded device Updated datsheet format | 4/14/15 |
| А | | 1 | Product Discontinuation Notice - Last Time Buy Expires September 7, 2016. PDN# N-16-02. | 3/10/16 |



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